

International Application No.: PCT/JP2004/000762
U.S. Patent Application No.: Unknown
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IN THE ABSTRACT:

Please replace the Abstract of the Disclosure originally filed with the above-identified patent application with the following new Abstract of the Disclosure:

ABSTRACT OF THE DISCLOSURE

A boundary acoustic wave device includes a LiNbO_3 substrate defining a first medium layer having a relatively high sound velocity and a SiO_2 film defining a second medium layer having a relatively low sound velocity, an electroacoustic transducer and reflectors disposed between the first medium layer and the second medium layer, and recess portions and/or protrusion portions provided in the upper surface of the SiO_2 film.